TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74ACT521P, TC74ACT521F, TC74ACT521FW

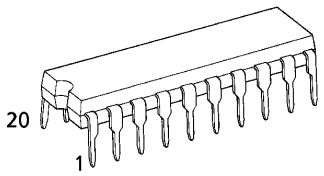
(Note) The JEDEC SOP (FW) is not available in Japan.

8 – BIT EQUALITY COMPARATOR

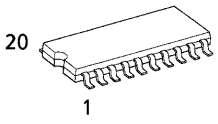
The TC74ACT521 is an advanced high speed CMOS 8-BIT DIGITAL COMPARATOR fabricated with silicon gate and double-layer metal wiring C^2MOS technology.
It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.
This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.
It compares two 8-bit binary or BCD words applied inputs P_0~P_7, and inputs Q_0~Q_7, and indicates whether or not they are equal.
A signal active low enable is provided to facilitate cascading of several packages to compare of words greater than 8 bits.
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES :

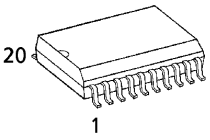
- High Speed ····· t_{pd} = 6.4ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ····· I_{CC} = 8μA(Max.) at Ta = 25°C
- Compatible with TTL outputs ····· V_{IL} = 0.8V (Max.)
  V_{IH} = 2.0V (Min.)
- Symmetrical Output Impedance ··· $|I_{OH}| = I_{OL}$ = 24mA(Min.)
  Capability of driving 50Ω transmission lines.
- Balanced Propagation Delays ····· $t_{pLH} \simeq t_{pHL}$
- Pin and Function Compatible with 74F521



P (DIP20-P-300-2.54A)
Weight : 1.30g (Typ.)

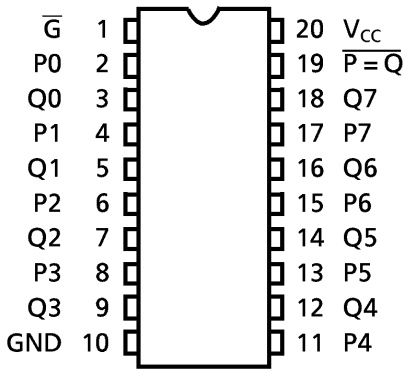


F (SOP20-P-300-1.27)
Weight : 0.22g (Typ.)



FW (SOL20-P-300-1.27)
Weight : 0.46g (Typ.)

PIN ASSIGNMENT



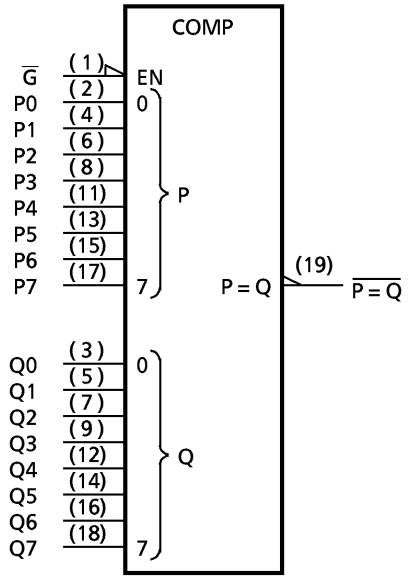
(TOP VIEW)

TRUTH TABLE

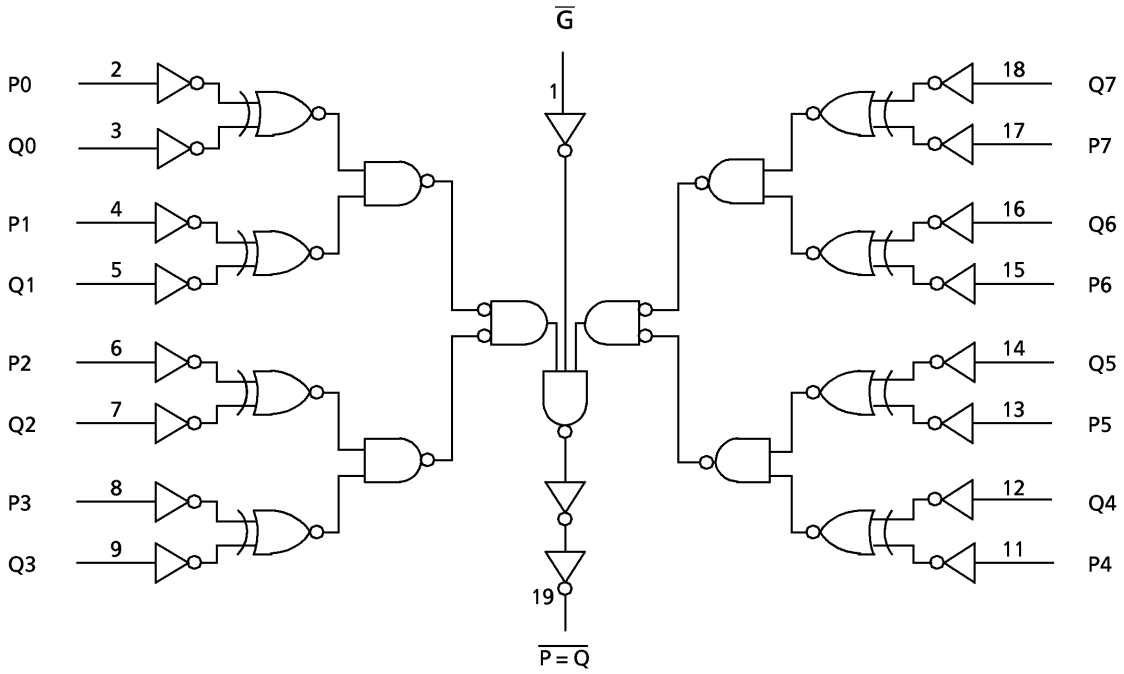
INPUTS		OUTPUT
P, Q	$\overline{G}$	$\overline{P = Q}$
P = Q	L	L
P ≠ Q	L	H
X	H	H

X : Don't Care

IEC LOGIC SYMBOL



SYSTEM DIAGRAM



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	−0.5~7.0	V
DC Input Voltage	V_{IN}	−0.5~V_{CC} + 0.5	V
DC Output Voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input Diode Current	I_{IK}	± 20	mA
Output Diode Current	I_{OK}	± 50	mA
DC Output Current	I_{OUT}	± 50	mA
DC V_{CC}/Ground Current	I_{CC}	± 100	mA
Power Dissipation	P_D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T_{stg}	−65~150	°C

*500mW in the range of Ta = −40°C~65°C. From Ta = 65°C to 85°C a derating factor of −10mW/°C should be applied up to 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~V_{CC}	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	dt / dV	0~10	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION		V_{CC} (V)	Ta = 25°C MIN.	Ta = 25°C TYP.	Ta = 25°C MAX.	Ta = −40~85°C MIN.	Ta = −40~85°C MAX.	UNIT
High - Level Input Voltage	V_{IH}			4.5 ~ 5.5	2.0	—	—	2.0	—	V
Low - Level Input Voltage	V_{IL}			4.5 ~ 5.5	—	—	0.8	—	0.8	V
High - Level Output Voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50μA I_{OH} = −24mA I_{OH} = −75mA*	4.5 4.5 5.5	4.4 3.94 —	4.5 — —	— — —	4.4 3.80 3.85	— — —	V
Low - Level Output Voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50μA I_{OL} = 24mA I_{OL} = 75mA*	4.5 4.5 5.5	— — —	0.0 — —	0.1 0.36 —	— — —	0.1 0.44 1.65	V
Input Leakage Current	I_{IN}	V_{IN} = V_{CC} or GND		5.5	—	—	± 0.1	—	± 1.0	μA
Quiescent Supply Current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	8.0	—	80.0	μA
	I_C	PER INPUT : V_{IN} = 3.4V OTHER INPUT : V_{CC} or GND		5.5	—	—	1.35	—	1.5	mA

* : This spec indicates the capability of driving 50Ω transmission lines.
One output should be tested at a time for a 10ms maximum duration.

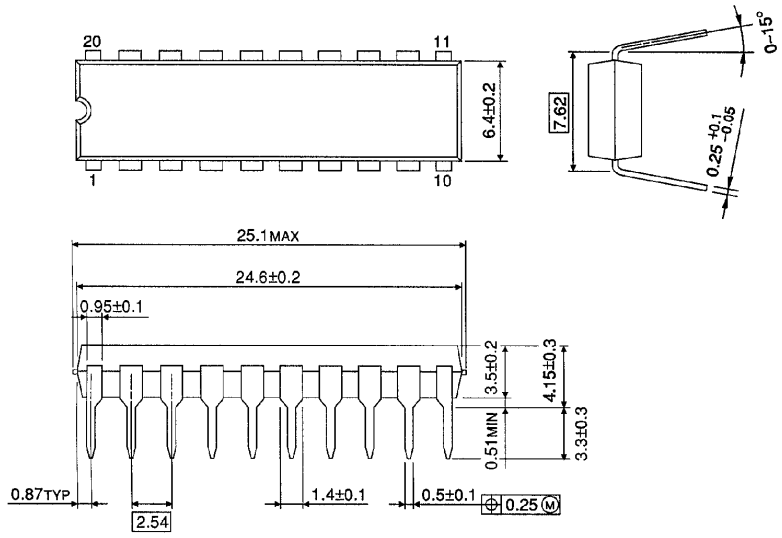
AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, R_L = 500Ω, Input $t_r = t_f$ = 3ns)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (Pn, Qn − $\overline{P=Q}$)	t_{pLH} t_{pHL}		5.0 ± 0.5	−	7.1	11.4	1.0	13.0	ns
Propagation Delay Time ($\overline{G}$ − $\overline{P=Q}$)	t_{pLH} t_{pHL}		5.0 ± 0.5	−	5.7	8.3	1.0	9.5	
Input Capacitance	C_{IN}			−	5	10	−	10	pF
Power Dissipation Capacitance	C_{PD} (1)			−	29	−	−	−	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:

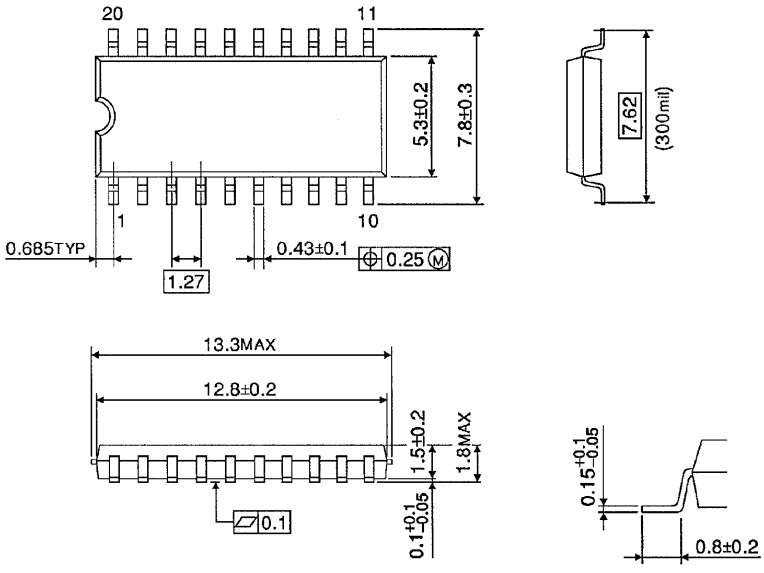
$$I_{CC}(opr.) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

DIP 20PIN PACKAGE DIMENSIONS (DIP20-P-300-2.54A) Unit in mm



Weight : 1.30g (Typ.)

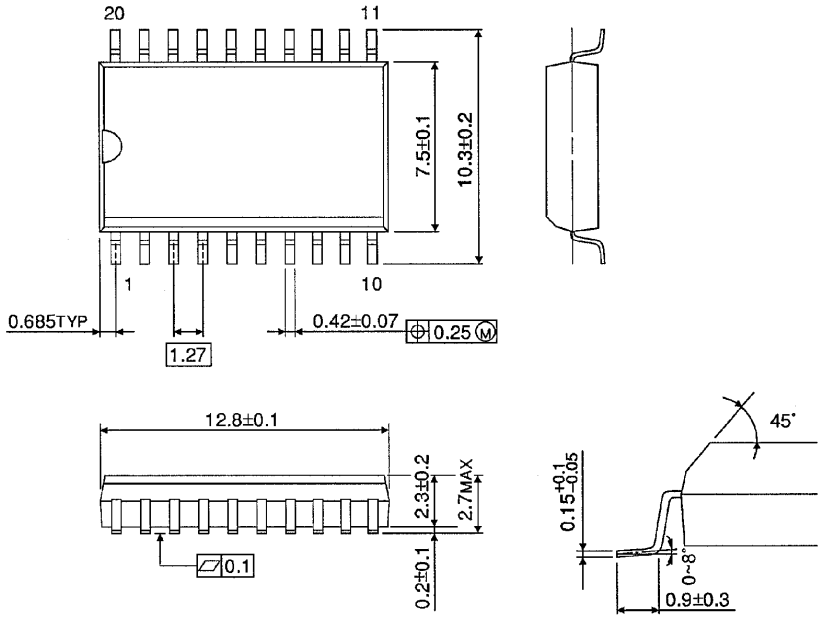
SOP 20PIN (200mil BODY) PACKAGE DIMENSIONS (SOP20-P-300-1.27) Unit in mm



Weight : 0.22g (Typ.)

SOP 20PIN (300mil BODY) PACKAGE DIMENSIONS (SOL20-P-300-1.27) Unit in mm

(Note) This package is not available in Japan.



Weight : 0.46g (Typ.)

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